

| | | | |
|---|--------------------|--|--|
| V_{DS} , 40V $R_{DS(ON)}$, 2.5m Ω (max.) @ $V_{GS}=10V$ $R_{DS(ON)}$, 2.8m Ω (max.) @ $V_{GS}=4.5V$ I_D , 100A <small>Note 3</small> | PDFN 5x6-8L | | |
| | | | |

| Description | Features |
|--|---|
| <p>The SG40N01LQ uses advanced Trench technology and designs to provide excellent $R_{DS(ON)}$ with low gate charge. This device is suitable for use in PWM, load switching and general purpose applications.</p> | <ul style="list-style-type: none"> • Low On-Resistance • Low Input Capacitance • Low Miller Charge • Low Input / Output Leakage • Pb-free lead plating; RoHS compliant |
| | Applications |
| | <ul style="list-style-type: none"> • Lithium-Ion Secondary Batteries • Load Switch • DC-DC converters and Off-line UPS |

Ordering Information

| Ordering Code | RoHS Status | Package | Package Code | Packing | Quantity |
|---------------|--------------|-------------|--------------|-------------|----------|
| SG40N01LQ | Halogen-Free | PDFN 5x6-8L | Q | Tape & Reel | 2,500 |

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|--|-----------|------------------------|---------------------------|
| Drain-Source Voltage | V_{DS} | 40 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Drain Current-Continuous <small>Note 1</small> | I_D | $T_C=25^\circ\text{C}$ | 100 <small>Note 3</small> |
| | | $T_C=70^\circ\text{C}$ | 100 <small>Note 3</small> |
| Drain Current-Pulsed <small>Note 1</small> | I_{DM} | 400 | A |
| Drain Current-Continuous | I_D | $T_A=25^\circ\text{C}$ | 31 |
| | | $T_A=70^\circ\text{C}$ | 25 |
| Avalanche Current | I_{AS} | 63.5 | A |
| Avalanche Energy, $L=0.1\text{mH}$ | E_{AS} | 201 | mJ |
| Maximum Power Dissipation | P_D | $T_C=25^\circ\text{C}$ | 83 |
| | | $T_C=70^\circ\text{C}$ | 53 |
| | | $T_A=25^\circ\text{C}$ | 3.6 |
| | | $T_A=70^\circ\text{C}$ | 2.3 |
| Storage Temperature Range | T_{STG} | -55 to +150 | $^\circ\text{C}$ |
| Operating Junction Temperature Range | T_J | -55 to +150 | $^\circ\text{C}$ |

Thermal Resistance Ratings

| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
|---|-----------------|--------------|------|------|------|--------------------|
| Maximum Junction-to-Ambient <small>Note 2</small> | $R_{\theta JA}$ | Steady State | - | - | 35 | $^\circ\text{C/W}$ |
| Maximum Junction-to-Case | $R_{\theta JC}$ | Steady State | - | - | 1.5 | $^\circ\text{C/W}$ |

Electrical Characteristics (T_J=25°C unless otherwise noted)

| OFF CHARACTERISTICS | | | | | | |
|---------------------------------|-------------------|---|------|------|------|------|
| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _{DS} =250μA | 40 | - | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =32V, V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage | I _{GSS} | V _{GS} =±20V, V _{DS} =0V | - | - | ±100 | nA |

| ON CHARACTERISTICS | | | | | | |
|----------------------------------|---------------------|---|------|------|------|------|
| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
| Gate Threshold Voltage | V _{GS(TH)} | V _{DS} =V _{GS} , I _{DS} =250μA | 1.3 | - | 2.4 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =10V, I _{DS} =30A | - | 2.2 | 2.5 | mΩ |
| Drain-Source On-State Resistance | R _{DS(ON)} | V _{GS} =4.5V, I _{DS} =15A | - | 2.5 | 2.8 | mΩ |

| DYNAMIC CHARACTERISTICS | | | | | | |
|------------------------------|------------------|---|------|------|------|------|
| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
| Input Capacitance | C _{iss} | V _{DS} =20V, V _{GS} =0V, f=1MHz | - | 4222 | - | pF |
| Output Capacitance | C _{oss} | | - | 889 | - | |
| Reverse Transfer Capacitance | C _{rss} | | - | 398 | - | |
| Gate Resistance | R _g | V _{GS} =0V, V _{DS} =0V, f=1MHz | - | 2.2 | 3 | Ω |

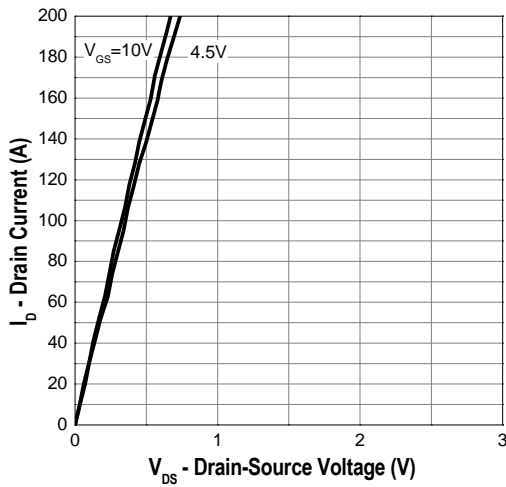
| SWITCHING CHARACTERISTICS | | | | | | |
|-------------------------------|---------------------|---|------|------|------|------|
| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
| Turn-On Delay Time | T _{d(on)} | V _{DS} =20V, I _{DS} =30A, V _{GS} =10V, R _{GEN} =3Ω | - | 21 | - | ns |
| Rise Time | t _r | | - | 6 | - | |
| Turn-Off Delay Time | T _{d(off)} | | - | 98 | - | |
| Fall Time | t _f | | - | 17 | - | |
| Total Gate Charge at 10V | Q _g | V _{DS} =20V, I _{DS} =30A, V _{GS} =10V | - | 78 | - | nC |
| Gate to Source Gate Charge | Q _{gs} | | - | 22 | - | |
| Gate to Drain "Miller" Charge | Q _{gd} | | - | 4.7 | - | |

| DRAIN-SOURCE DIODE CHARACTERISTICS AND MAXIMUM RATINGS | | | | | | |
|--|-----------------|---|------|------|------|------|
| Parameter | Symbol | Conditions | Min. | Typ. | Max. | Unit |
| Drain-Source Diode Forward Voltage | V _{SD} | V _{GS} =0V, I _{DS} =30A | - | - | 1.3 | V |
| Body Diode Reverse Recovery Time | t _{rr} | I _F =30A, di/dt=100A/μs | - | 32 | - | ns |
| Body Diode Reverse Recovery Charge | Q _{rr} | | - | 120 | - | nC |

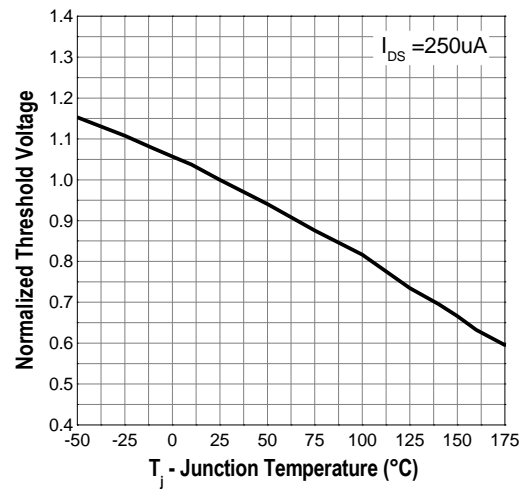
- Notes:**
1. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
 2. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{θJC} is guaranteed by design while R_{θJA} is determined by the user's board design. R_{θJA} shown below for single device operation on FR-4 in still air.
 3. The maximum current rating is limited by package.

Typical Operating Characteristics

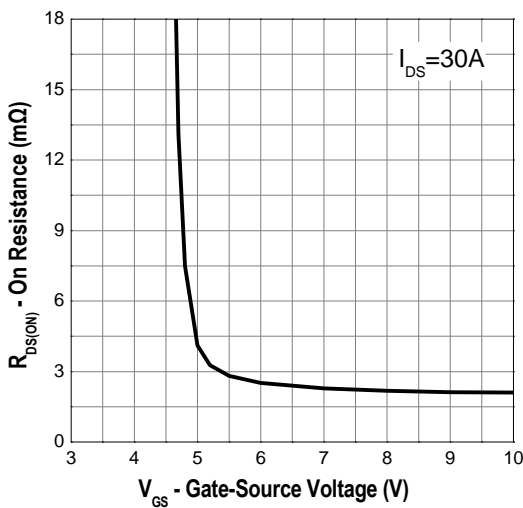
Output Characteristics



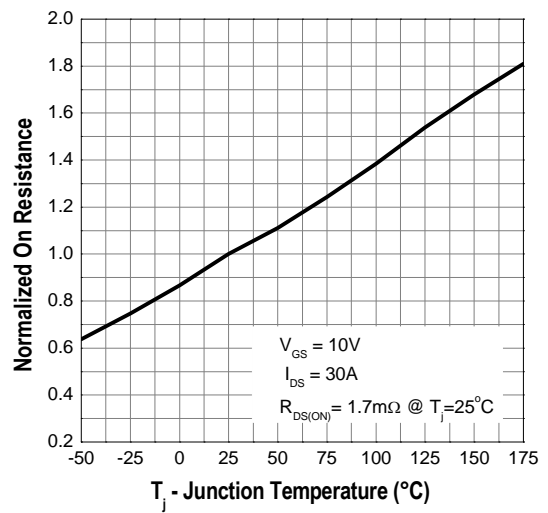
Gate Threshold Voltage



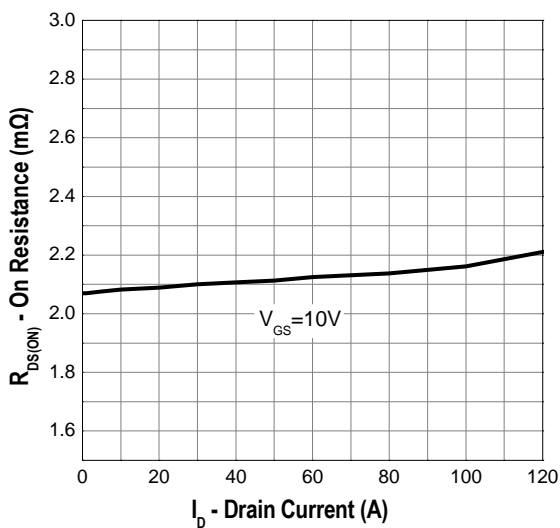
Gate-Source On Resistance



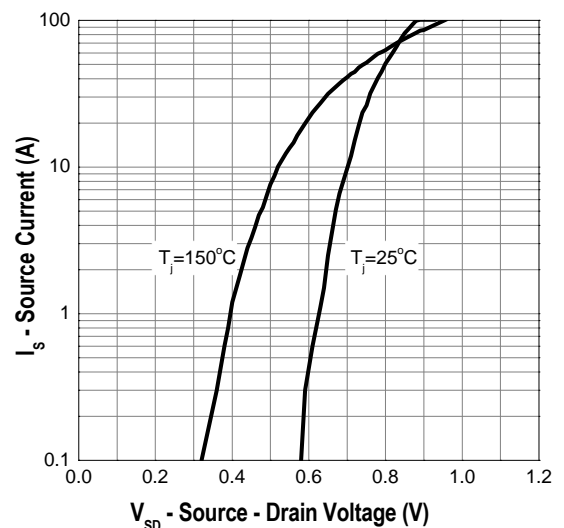
Drain-Source On Resistance



Drain-Source On Resistance

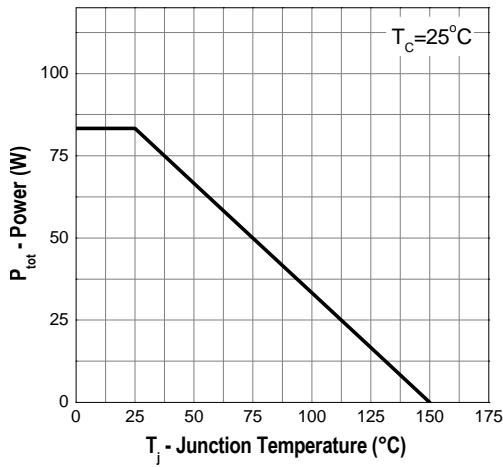


Source-Drain Diode Forward

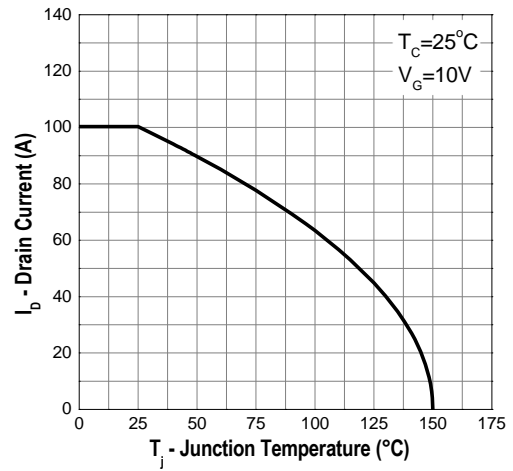


Typical Operating Characteristics (Cont.)

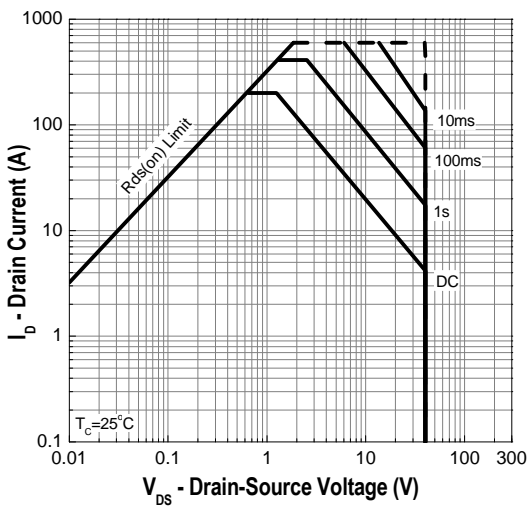
Power Dissipation



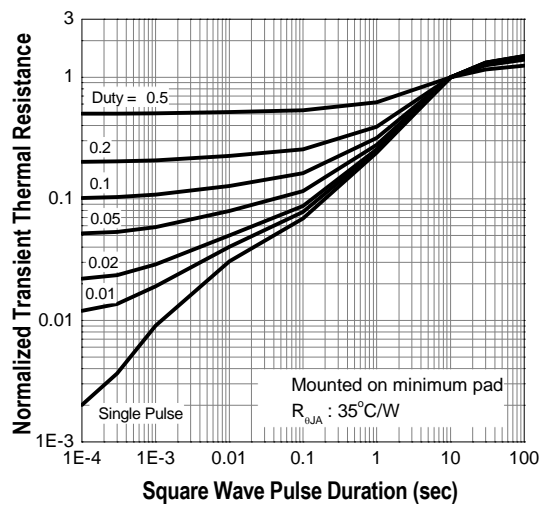
Drain Current



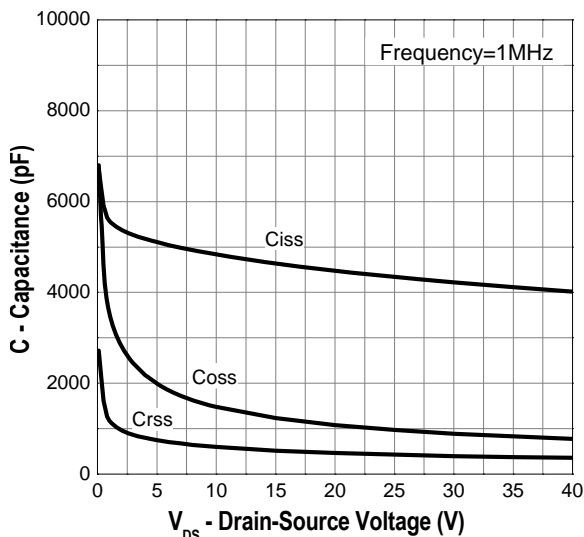
Safe Operation Area



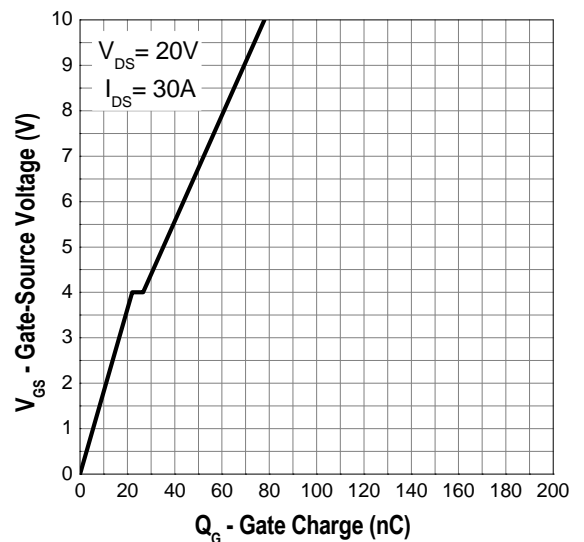
Transient Thermal Impedance



Capacitance



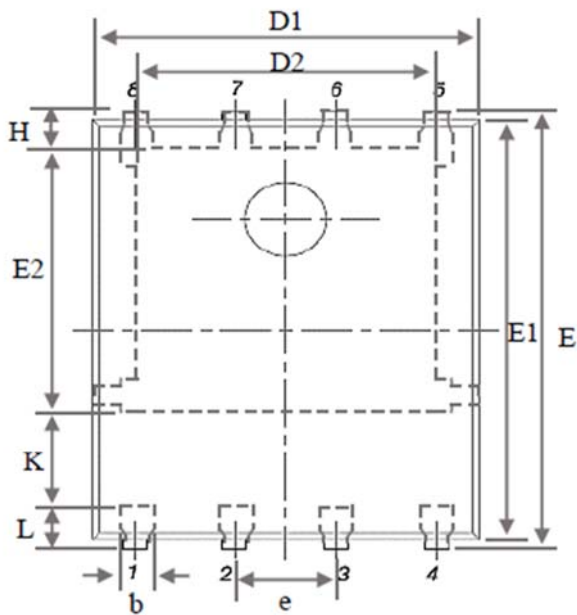
Gate Charge



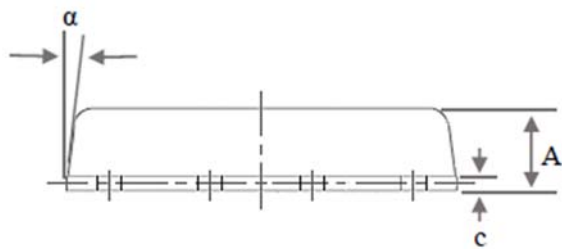
Marking Information

| PDFN 5x6-8L (Q) | Marking Rule |
|--|--|
| <p>Laser Marking</p> <div data-bbox="306 454 600 741" style="text-align: center;"> </div> <p>Diagram</p> | <p><u>Line 1</u> : Device SG40N01LQ</p> <p><u>Line 2</u> : Date Code YYMMXXX</p> <p>YY : Year Code MM : Month Code XXX : Serial Number</p> |

Package of Dimension



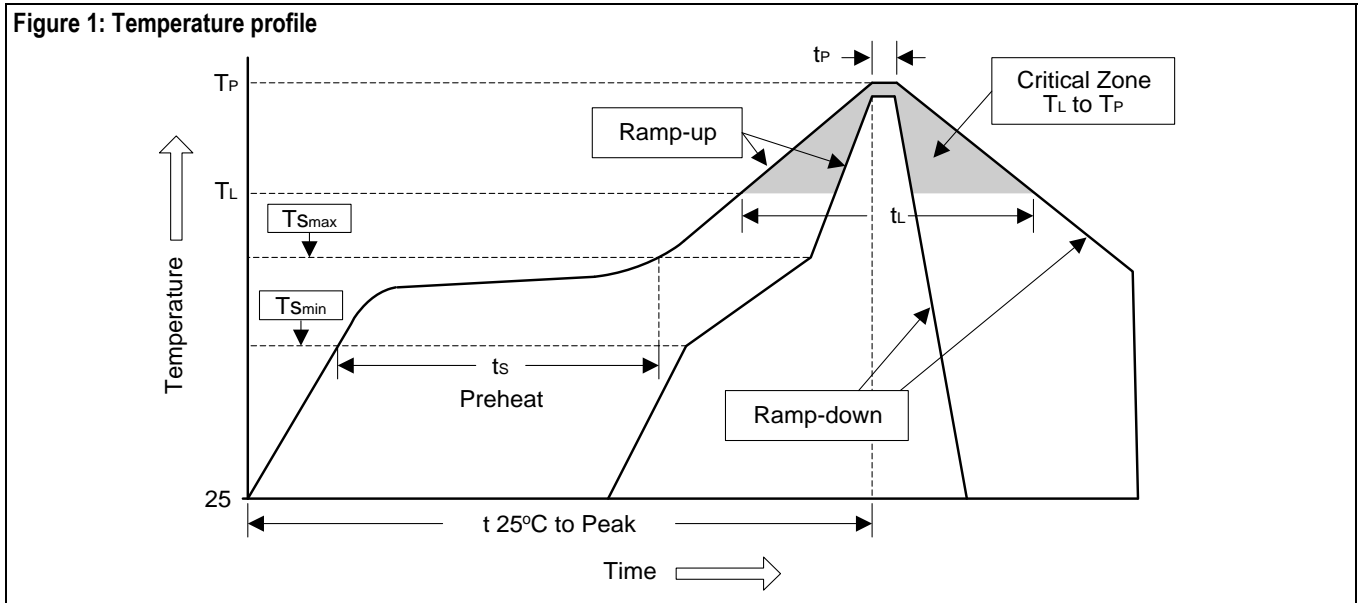
| Symbol | Min | Nor | Max |
|--------|----------|------|------|
| A | 0.90 | 1.04 | 1.17 |
| b | 0.33 | 0.42 | 0.51 |
| C | 0.06 | 0.20 | 0.35 |
| D1 | 4.80 | 5.10 | 5.40 |
| D2 | 3.61 | 3.96 | 4.31 |
| E | 5.90 | 6.03 | 6.15 |
| E1 | 5.65 | 5.75 | 5.85 |
| E2 | 3.30 | 3.54 | 3.78 |
| e | 1.27 BSC | | |
| H | 0.38 | 0.50 | 0.61 |
| L | 0.38 | 0.55 | 0.71 |
| L1 | 0.05 | 0.15 | 0.25 |



Soldering Methods for Silicongear's Products

1. Storage environment: Temperature=10°C to 35°C Humidity=65%±15%
2. Reflow soldering of surface-mount devices

Figure 1: Temperature profile



| Profile Feature | Sn-Pb Eutectic Assembly | Pb-Free Assembly |
|--|-------------------------|------------------|
| Average ramp-up rate (T_L to T_P) | <3°C/sec | <3°C/sec |
| Preheat | | |
| - Temperature Min (T_{Smin}) | 100°C | 150°C |
| - Temperature Max (T_{Smax}) | 150°C | 200°C |
| - Time (min to max) (t_s) | 60 to 120 sec | 60 to 180 sec |
| T_{Smax} to T_L | | |
| - Ramp-up Rate | <3°C/sec | <3°C/sec |
| Time maintained above: | | |
| - Temperature (T_L) | 183°C | 217°C |
| - Time (t_L) | 60 to 150 sec | 60 to 150 sec |
| Peak Temperature (T_P) | 240°C +0/-5°C | 260°C +0/-5°C |
| Time within 5°C of actual Peak Temperature (t_P) | 10 to 30 sec | 20 to 40 sec |
| Ramp-down Rate | <6°C/sec | <6°C/sec |
| Time 25°C to Peak Temperature | <6 minutes | <8 minutes |

3. Flow (wave) soldering (solder dipping)

| Products | Peak Temperature | Dipping Time |
|------------------|------------------|--------------|
| Pb devices. | 245°C ±5°C | 5sec ±1sec |
| Pb-Free devices. | 260°C +0/-5°C | 5sec ±1sec |

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